

# International Rectifier

HEXFRED™

**Features**

- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low  $I_{RRM}$
- Very Low  $Q_{rr}$
- Specified at Operating Conditions
- Lead-Free

**Benefits**

- Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count

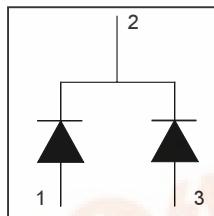
**Description**

International Rectifier's HFA08TA60C is a state of the art center tap ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 4 amps per Leg continuous current, the HFA08TA60C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current ( $I_{RRM}$ ) and does not exhibit any tendency to "snap-off" during the  $t_b$  portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TA60C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

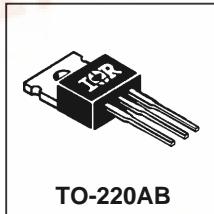
**Absolute Maximum Ratings**

	Parameter	Max	Units
$V_R$	Cathode-to-Anode Voltage	600	V
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	4.0	A
$I_{FSM}$	Single Pulse Forward Current	25	
$I_{FRM}$	Maximum Repetitive Forward Current	16	
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	25	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	10	
$T_J$	Operating Junction and Storage Temperature Range	- 55 to +150	C
$T_{STG}$			

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$V_R = 600V$
$V_F = 1.8V$
$Q_{rr} * = 40nC$
$dI_{(rec)}/dt * = 280A/\mu s$ * $125^\circ C$

**HFA08TA60CPbF**

Ultrafast, Soft Recovery Diode

HFA08TA60CPbF

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**Electrical Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)**

	Parameter	Min	Typ	Max	Units	Test Conditions
$V_{BR}$	Cathode Anode Breakdown Voltage	600			V	$I_R = 100\mu\text{A}$
$V_{FM}$	Max Forward Voltage	1.5	1.8			$I_F = 4.0\text{A}$
		1.8	2.2		V	$I_F = 8.0\text{A}$
		1.4	1.7			$I_F = 4.0\text{A}, T_J = 125^\circ\text{C}$
$I_{RM}$	Max Reverse Leakage Current	0.17	3.0		$\mu\text{A}$	$V_R = V_R \text{ Rated}$
		44	300			$T_J = 125^\circ\text{C}, V_R = 0.8 \times V_R \text{ Rated}$
$C_T$	Junction Capacitance	4.0	8.0		pF	$V_R = 200\text{V}$
$L_S$	Series Inductance		8.0		nH	Measured lead to lead 5mm from package body

**Dynamic Recovery Characteristics @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)**

	Parameter	Min	Typ	Max	Units	Test Conditions
$t_{rr}$	Reverse Recovery Time See Fig. 5, 6 & 16	17				$I_F = 1.0\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$
		28	42		ns	$T_J = 25^\circ\text{C}$
		38	57			$T_J = 125^\circ\text{C}$
$I_{RRM1}$	Peak Recovery Current See Fig. 7 & 8	2.9	5.2		A	$T_J = 25^\circ\text{C}$
		3.7	6.7			$T_J = 125^\circ\text{C}$
$I_{RRM2}$	Reverse Recovery Charge See Fig. 9 & 10	40	60		nC	$T_J = 25^\circ\text{C}$
		70	105			$T_J = 125^\circ\text{C}$
$di_{(rec)M}/dt_1$	Peak Rate of Fall of Recovery Current During $t_b$ See Fig. 11 & 12	280			A/ $\mu\text{s}$	$T_J = 25^\circ\text{C}$
		235				$T_J = 125^\circ\text{C}$

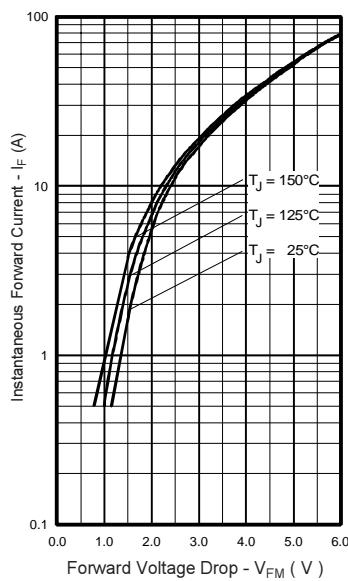
**Thermal - Mechanical Characteristics**

	Parameter	Min	Typ	Max	Units
$T_{lead}^{\circledR}$	Lead Temperature			300	°C
$R_{thJC}^{\circledR}$	Thermal Resistance, Junction to Case			5.0	
$R_{thJA}^{\circledR}$	Thermal Resistance, Junction to Ambient			80	K/W
$R_{thCS}^{\circledR}$	Thermal Resistance, Case to Heat Sink		0.5		
$W_t$	Weight		2.0		g
			0.07		(oz)
$T$	Mounting Torque	6.0		12	Kg-cm
		5.0		10	lbf-in

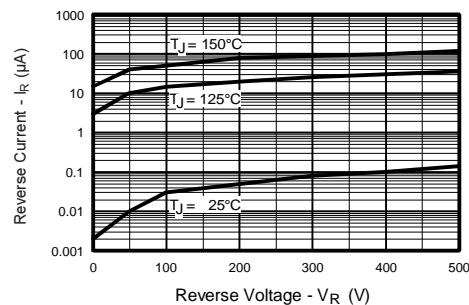
- ① 0.063 in. from Case (1.6mm) for 10 sec
- ② Typical Socket Mount
- ③ Mounting Surface, Flat, Smooth and Greased

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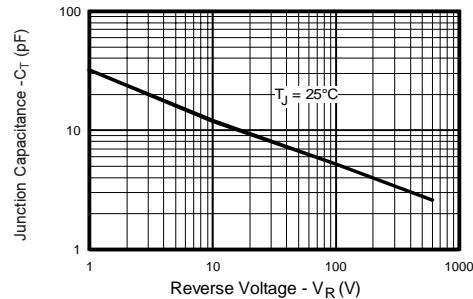
HFA08TA60CPbF



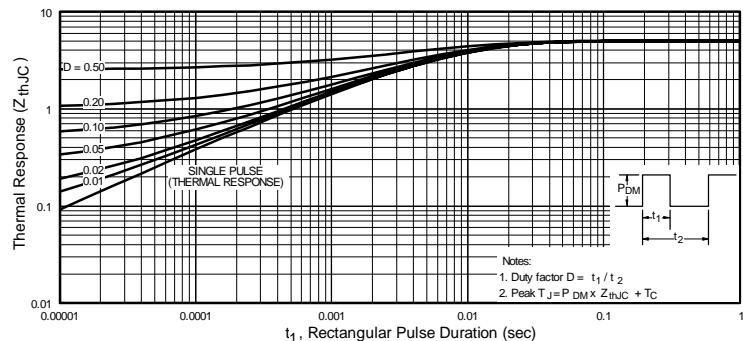
**Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current,**



**Fig. 2 - Typical Reverse Current vs. Reverse Voltage**



**Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage**



**Fig. 4 - Maximum Thermal Impedance  $Z_{thjc}$  Characteristics**

## HFA08TA60CPbF

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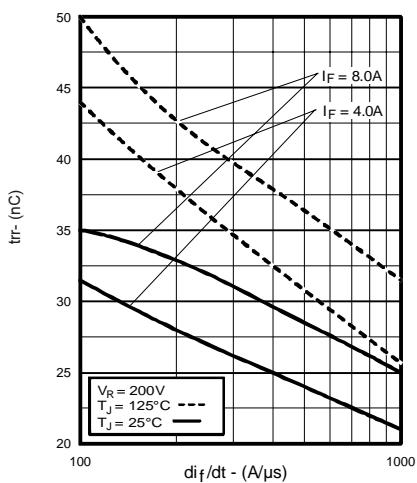


Fig. 5 - Typical Reverse Recovery vs.  $di_r/dt$

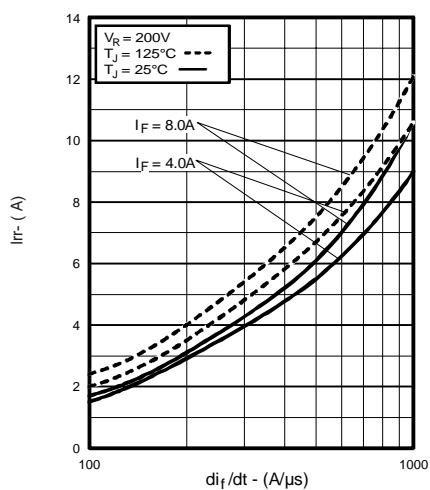


Fig. 6 - Typical Recovery Current vs.  $di_r/dt$

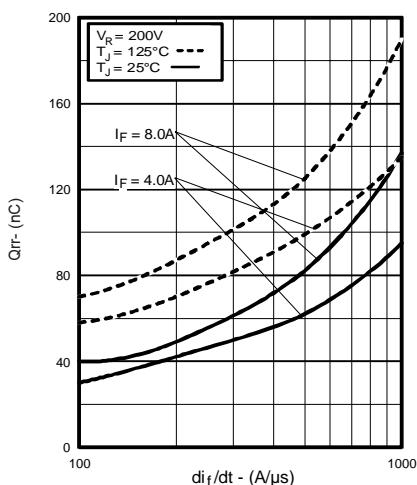


Fig. 7 - Typical Stored Charge vs.  $di_r/dt$

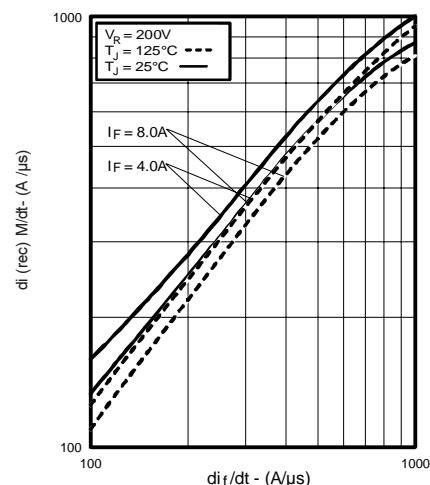
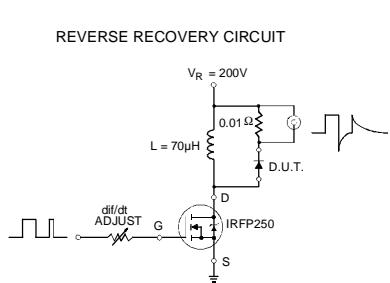
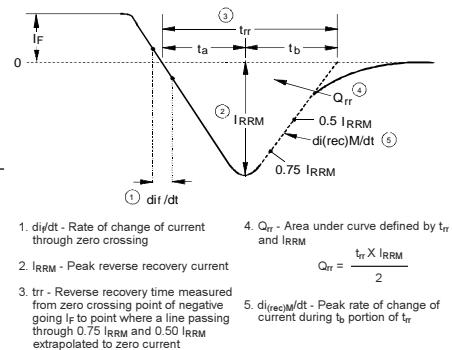


Fig. 8 - Typical  $di_{(rec)}/dt$  vs.  $di_r/dt$ ,



**Fig. 9 - Reverse Recovery Parameter Test Circuit**

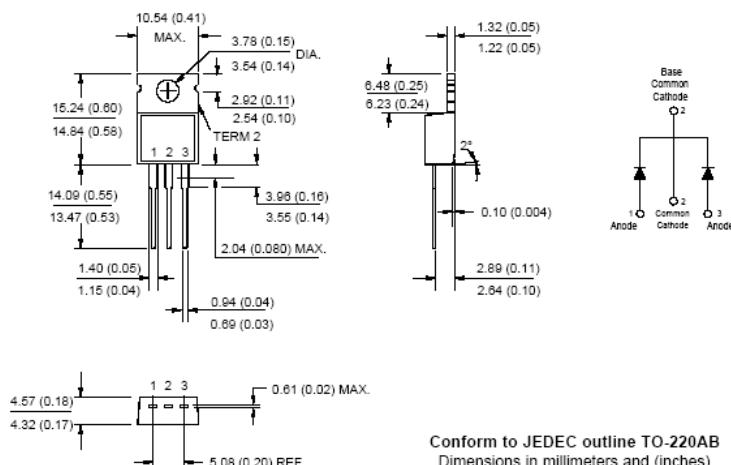


**Fig. 10 - Reverse Recovery Waveform and Definitions**

## HFA08TA60CPbF

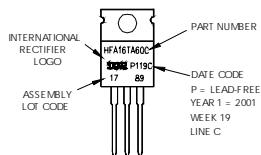
### TO-220AB Package Outline

Dimensions are shown in millimeters (inches)



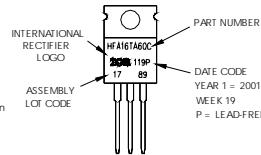
### TO-220AB Part Marking Information

EXAMPLE: THIS IS A HFA16TA60C  
LOT CODE 1789  
ASSEMBLED ON WW 19, 2001  
IN THE ASSEMBLY LINE "C"  
Note: "P" in the beginning of date code indicates "Lead-Free"



OR

EXAMPLE: THIS IS A HFA16TA60C  
LOT CODE 1789  
ASSEMBLED ON WW 19, 2001  
Note: "P" in assembly line position  
indicates "Lead-Free"



Data and specifications subject to change without notice.

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